

RELIABILITY REPORT

FOR

MAX4453EKA+T

PLASTIC ENCAPSULATED DEVICES

August 6, 2010

# **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by
Don Lipps
Quality Assurance
Manager, Reliability Engineering



#### Conclusion

The MAX4453EKA+T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

#### **Table of Contents**

IDevice Description	VQuality Assurance Information
IIManufacturing Information	VIReliability Evaluation
IIIPackaging Information	IVDie Information
Attachments	

#### I. Device Description

A. General

The MAX4452/MAX4352 single, MAX4453/MAX4453 dual, and MAX4454/MAX4354 quad amplifiers combine high-speed performance with ultra-low power consumption. The MAX4452/MAX4453/MAX4454 are unity-gain stable and achieve a -3dB bandwidth of 200MHz, while the MAX4352/MAX4353/MAX4354 are compensated for a minimum closed-loop gain of +5V/V and achieve a 80MHz -3dB bandwidth. These devices consume only 620µA of supply current per amplifier. These amplifiers operate from a +2.7V to +5.25V single supply and feature rail-to-rail outputs. Along with an excellent speed/power ratio of 323MHz/mA, these devices feature a slew rate of 95V/µs and fast 20ns rise and fall times. These devices are ideal for low-power/low-voltage systems that require wide bandwidth such as cell phones and keyless entry systems. The MAX4452/MAX4352 are available in miniature 5-pin SC70 and SOT23 packages, while the MAX4453/MAX4353 are available in tiny 8-pin SOT23, thin SOT23, and SO packages. The MAX4454/MAX4354 are available in space-saving 14-pin TSSOP and SO packages.



#### II. Manufacturing Information

A. Description/Function: Low-Cost, +3V/+5V, 620µA, 200MHz, Single-Supply Op Amps with

Rail-to-Rail Outputs

B. Process: CB3

C. Number of Device Transistors:

D. Fabrication Location: Oregon

E. Assembly Location: Malaysia, ThailandF. Date of Initial Production: January 27, 2001

#### III. Packaging Information

A. Package Type: 8-pin SOT23
B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin
D. Die Attach: Conductive
E. Bondwire: Au (1 mil dia.)

F. Mold Material: Epoxy with silica filler
G. Assembly Diagram: #05-2501-0047
H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per

JEDEC standard J-STD-020-C

J. Single Layer Theta Jb:

110\*°C/W 80°C/W

Level 1

K. Single Layer Theta Jc: 80°C/W
L. Multi Layer Theta Ja: n/a°C/W
M. Multi Layer Theta Jc: n/a°C/W

### IV. Die Information

A. Dimensions: 67 X 24 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub> (Silicon nitride)

C. Interconnect: Au
D. Backside Metallization: None

E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
 F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.
H. Isolation Dielectric: SiO<sub>2</sub>
I. Die Separation Method: Wafer Saw



#### V. Quality Assurance Information

A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm
D. Sampling Plan: Mil-Std-105D

# VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 80 \times 2}$$
 (Chi square value for MTTF upper limit)  

$$(\text{where } 4340 \times 80 \times 2)$$
 (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)  

$$\lambda = 13.7 \times 10^{-9}$$

$$\lambda = 13.7 \text{ F.I.T. } (60\% \text{ confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim"s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the CB3 Process results in a FIT Rate of 0.25 @ 25C and 4.38 @ 55C (0.8 eV, 60% UCL)

#### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

#### C. E.S.D. and Latch-Up Testing

The OX16 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250mA.



# **Table 1**Reliability Evaluation Test Results

# MAX4453EKA+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test (N	lote 1)				
·	Ta = 150°C	DC Parameters	80	0	
	Biased	& functionality			
	Time = 192 hrs.	·			
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stress	(Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	•			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data